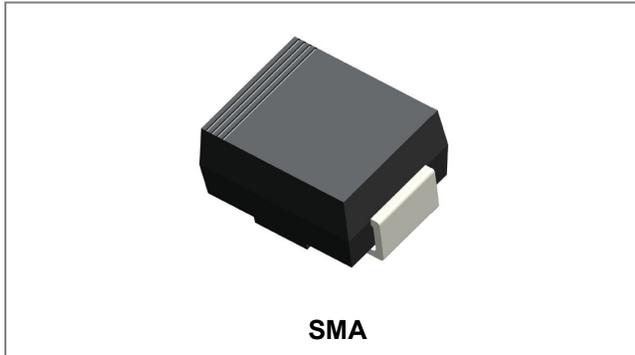


SL36A SCHOTTKY RECTIFIER



Features

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- High Current Capability
- Low Power Loss, High Efficiency
- High Surge Current Capability
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- Terminals finish: Tin Lead-free plated
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings@ $T_A=25^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	-	60	V
Average Rectified Forward Current	$I_{F(AV)}$	50% duty cycle @ $T_c=105^\circ\text{C}$, rectangular wave form	3	A
Peak One Cycle Non-Repetitive Surge Current	I_{FSM}	8.3ms, Half Sine pulse	70	A

Electrical Characteristics:

Characteristics	Symbol	Condition	Typ.	Max.	Units
Forward Voltage Drop*	V_{F1}	@ 3A, Pulse, $T_J = 25^\circ\text{C}$	0.53	0.58	V
	V_{F2}	@ 3A, Pulse, $T_J = 125^\circ\text{C}$	0.50	0.53	V
Reverse Current*	I_{R1}	@ $V_R = \text{rated } V_R, T_J = 25^\circ\text{C}$	0.02	1.0	mA
	I_{R2}	@ $V_R = \text{rated } V_R, T_J = 125^\circ\text{C}$	14	55	mA
Junction Capacitance	C_j	@ $V_R = 5.0\text{ V}, T_c=25^\circ\text{C}$ $f_{SIG} = 1\text{MHz}$	123	250	pF
Series Inductance	L_s	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/ μs

* Pulse width < 300 μs , duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	T_J	-	-55 to +125	°C
Storage Temperature	T_{stg}	-	-55 to +125	°C
Typical Thermal Resistance Junction to Case	$R_{\theta JC}$	-	8	°C/W
Approximate Weight	wt	-	0.06	g

Ratings and Characteristics Curves

Figure 1 Typical Forward Characteristics

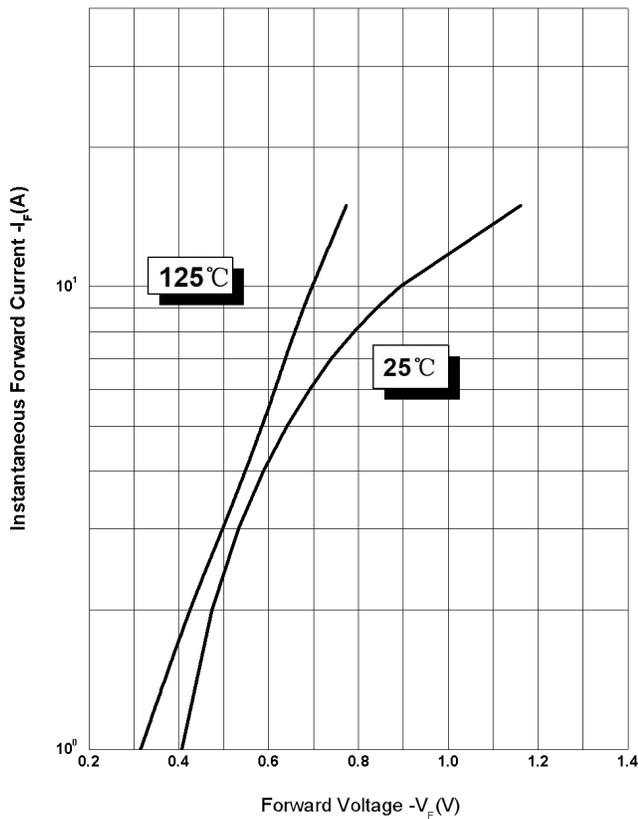


Figure 2 Typical Reverse Characteristics

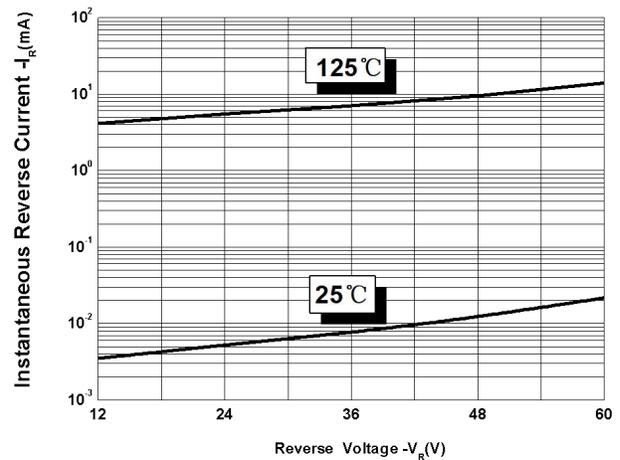
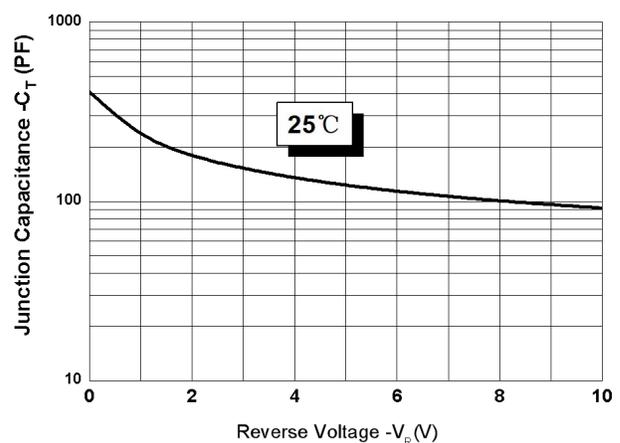
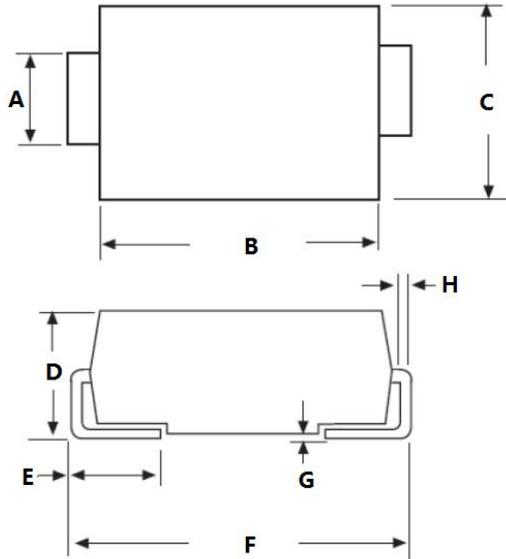


Figure 3 Typical Junction Capacitance



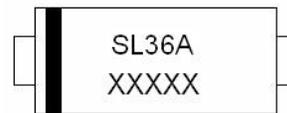
Mechanical Dimensions SMA


SYMBOL	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	1.25	1.65	0.049	0.065
B	3.95	4.60	0.156	0.181
C	2.25	2.95	0.089	0.116
D	1.95	2.90	0.077	0.114
E	0.75	1.60	0.030	0.063
F	4.80	5.60	0.189	0.220
G	0.05	0.20	0.002	0.008
H	0.15	0.41	0.006	0.016

Ordering Information

Device	Package	Shipping
SL36A	SMA (Pb-Free)	5000pcs / reel
SL36ATR	SMA (Pb-Free)	5000pcs / reel

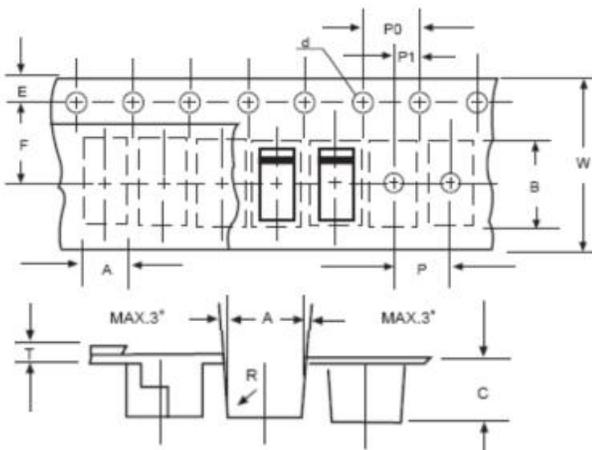
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram


Where XXXXX is YYWWL

- SL = Device Type
- 3 = Forward Current (3A)
- 6 = Reverse Voltage (60V)
- A = Package type
- YY = Year
- WW = Week
- L = Lot Number

Cautions: Molding resin
Epoxy resin UL:94V-0

Carrier Tape Specification SMA


SYMBOL	Millimeters	
	Min.	Max.
A	2.97	3.17
B	5.70	5.90
C	2.32	2.52
d	1.40	1.60
E	1.40	1.60
F	5.60	5.70
P	3.90	4.10
P0	3.90	4.10
P1	1.90	2.10
T	0.25	0.35
W	11.80	12.20

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